



KBJ6005 THRU KBJ610

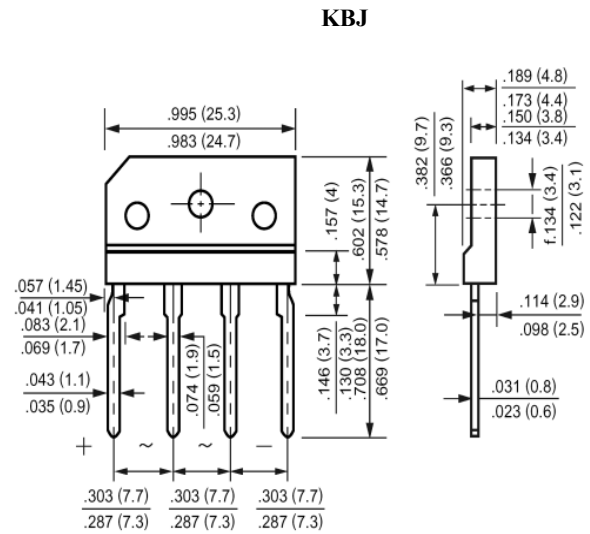
Reverse Voltage - 50 to 1000 Volts Forward Current - 6.0 Amperes

Features

- Glass passivated chip junction
- Reliable low cost construction utilizing molded plastic technique
- Ideal for printed circuit board
- Low forward voltage drop
- Low reverse leakage current
- High surge current capability

Mechanical Data

- Case: Molded plastic, KBJ
- Epoxy: UL 94V-O rate flame retardant
- Terminals: Leads solderable per MIL-STD-202, method 208 guaranteed
- Mounting position: Any
- Weight: 0.16ounce, 4.6gram



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60ZH resistive or inductive load.
 For capacitive load, derate current by 20%.

	Symbols	KBJ6005	KBJ601	KBJ602	KBJ604	KBJ606	KBJ608	KBJ610	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at $T_A=110$	$I_{(AV)}$	6.0							Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	120							Amp
Maximum Forward Voltage at 3.0A DC and 25	V_F	1.0							Volts
Maximum Reverse Current at $T_A=25$ at Rated DC Blocking Voltage $T_A=125$	I_R	5.0							uAmp
Typical Junction Capacitance (Note 1)	C_J	80							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JC}$	1.5							/W
Operating and Storage Temperature Range	T_J, T_{stg}	-55 to +150							

NOTES:

- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
- Thermal Resistance from Junction to Case with Device Mounted on 75mm x 75mm x 1.6mmCu Plate Heatsink.



KBJ6005 THRU KBJ610

Reverse Voltage - 50 to 1000 Volts Forward Current - 6.0 Amperes

Characteristic Curves ($T_A=25\text{ }^\circ\text{C}$ unless otherwise noted)

FIG.1-MAXIMUM FORWARD SURGE CURRENT

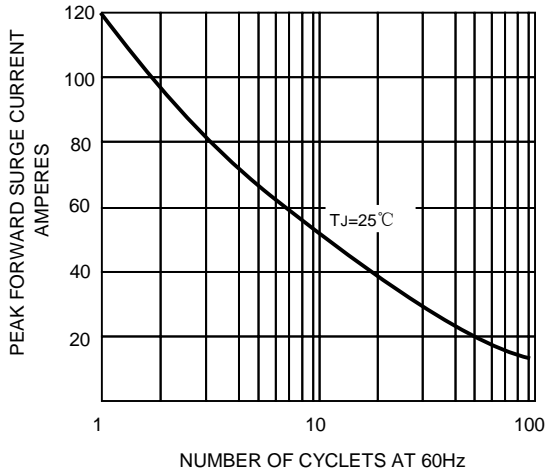


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

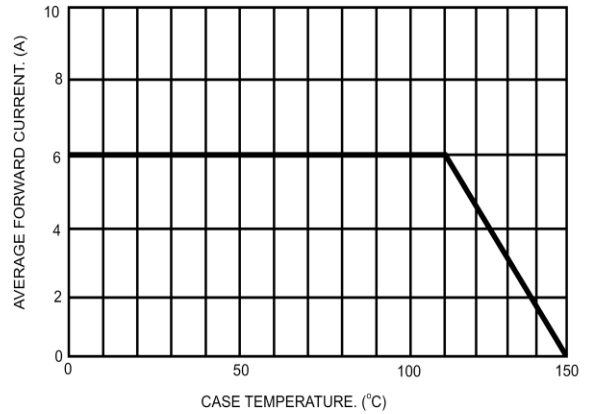


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER BRIDGE ELEMENT

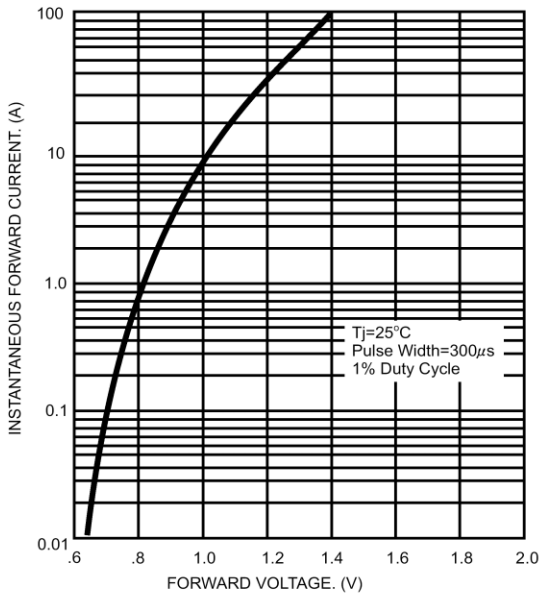
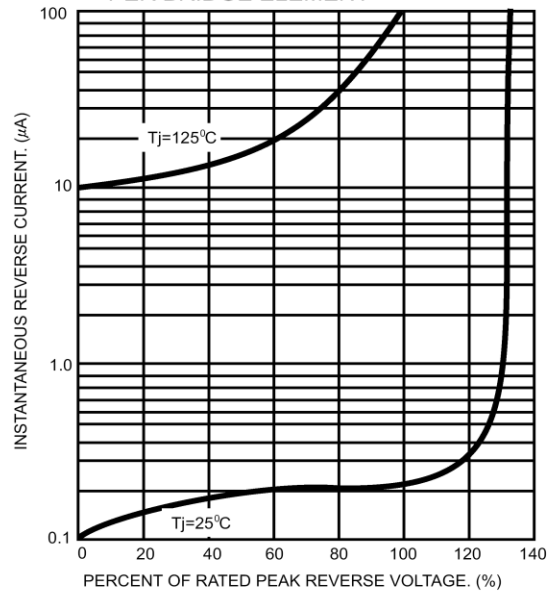


FIG.4- TYPICAL REVERSE CHARACTERISTICS PER BRIDGE ELEMENT



单击下面可查看定价，库存，交付和生命周期等信息

[>>ZG\(中鑫半导体\)](#)